



BASIC PRINCIPLES OF RF SUPERCONDUCTIVITY

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Outline

- Electrical conduction: DC and RF
- Superconductivity
 - Type-I and type-II superconductors
 - Intro to BCS and GL theories
- Surface impedance of superconductors
- DC and RF critical fields
- Field dependence of surface resistance
- Intro to performance limitations





DC electrical conduction: resistance



Drude Model electrons (shown here in blue) constantly bounce between heavier, stationary crystal ions (shown in red).

Average momentum of an electron in an electric field within the time between collision, τ

$$\langle p \rangle = eE\tau$$

 $\tau = l/v_F \approx 10^{-14}$ s is the electrons' scattering time

$$J = \frac{n e^2}{m \tau} E = \sigma E$$

Ohm's law, <u>local</u> relation between J and E





Electrodynamics of normal conductors



For accelerator applications, the rate of oscillation of the e.m. field is in the **radio-frequency (RF)** range (3 kHz – 300 GHz)

$$\nabla \cdot E = \frac{\rho}{\varepsilon_0} \qquad \nabla \times E = -\frac{\partial B}{\partial t}$$
$$\nabla \cdot B = 0 \qquad \nabla \times H = J + \frac{\partial D}{\partial t}$$

$$D = \varepsilon_0 \varepsilon E$$
$$B = \mu_0 \mu H$$
$$J = f(E)$$

(linear and isotropic) material's equations

- Maxwell's equations
- From Drude's model:

$$\frac{\partial J}{\partial t} + \frac{J}{\tau} = \frac{n e^2}{m} E \qquad \qquad J = \frac{\sigma}{\left(1 + i\omega\tau\right)} E = \sigma E$$

 $\omega \tau \ll 1$ at RF frequencies





Skin depth

For a good conductor at RF frequencies, $\omega \epsilon << \sigma \rightarrow \partial D / \partial t \sim 0$

 $\nabla \times \nabla \times H = \nabla (\nabla \cdot H) - \nabla^2 H = \sigma \nabla \times E = -i\mu_0 \mu \sigma \omega H$

 $\nabla^2 H = i \sigma \mu_0 \mu \omega H$ similar equations for *E* and *J*

Solution (semi-infinite slab):

$$H_{y} = H_{0}e^{-i\chi}e^{-i\chi}\delta$$
$$E_{z} = -\frac{(1+i)}{\sigma\delta}H_{y}$$

$$\delta = \sqrt{\frac{2}{\mu_0 \mu \sigma \omega}}$$







Surface Impedance

• The surface impedance is defined as:

$$Z = \frac{\left|E_{\parallel}\right|}{\int_{0}^{\infty} J(x)dx} = \frac{E_{\parallel}}{H_{\parallel}} = \underbrace{R_{s}}_{s} + i\underbrace{X_{s}}_{s}$$
surface reactance surface resistance

• For the semi-infinite plane conductor:

$$Z_{n} = \frac{\left|E_{z}(0)\right|}{H_{y}(0)} = \frac{1+i}{\sigma\delta} \qquad \qquad R_{s} = X_{s} = \frac{1}{\sigma\delta} = \sqrt{\frac{\mu_{0}\mu\omega}{2\sigma}}$$

• The impedance of vacuum is: $Z_0 = \left(\frac{\mu_0}{\varepsilon_0}\right)^{1/2} \simeq 377\Omega$





Example

Surface resistance of Cu at 300 K, 1.5 GHz:

```
\label{eq:sigma_state} \begin{split} \sigma(300\text{ K}) &= 5.8{\times}10^7\text{ }1{/}\Omega\text{m} \\ \mu_0 &= 1.26{\times}10^{\text{-6}}\text{ Vs/Am} \\ \mu &= 1 \end{split}
```

$$\implies \delta = 1.7 \ \mu m, R_s = 10 \ m\Omega$$





What happens at low temperature?

- $\sigma(T)$ increases, δ decreases \longrightarrow The skin depth (the distance over which fields vary) can become less than the mean free path of the electrons (the distance they travel before being scattered) $\longrightarrow J(x) \neq \sigma E(x)$
- Introduce a new relationship where *J* is related to *E* over a volume of the size of the mean free path (*l*)

$$\vec{J}(\vec{r},t) = \frac{3\sigma}{4\pi l} \int_{V} d\vec{r}' \frac{\vec{R} \left[\vec{R} \cdot \vec{E}(\vec{r}',t-\vec{R}/v_F) \right]}{R^4} e^{-R/l} \quad \text{with} \quad \vec{R} = \vec{r}' - \vec{r}$$

Effective conductivity $\sigma_{eff} \approx \frac{\delta}{l} \sigma = \frac{\delta}{l} \frac{n e_l^2 \hat{l}}{m v_{E'}}$

Contrary to the DC case higher purity (longer *l*) does not increase the conductivity \rightarrow anomalous skin effect





Anomalous skin effect

$$Z_n = \frac{4}{9} \left(\frac{\mu_0^2}{2\pi} \sqrt{3} \right)^{1/3} \left(\frac{l}{\sigma} \right)^{1/3} \omega^{2/3} (1 + \sqrt{3}i) \qquad l >> \delta$$

- $l/\sigma = mv_{\rm F}/e^2n$ is a constant for each material ~ 7×10⁻¹⁶ $\Omega {\rm m}^2$
- Independent of temperature





Example

Surface resistance of Cu at 1.5 GHz as a function of temperature

 $\rho l = 6.6 \times 10^{-16} \ \Omega m^2$

 $\rho(273 \text{ K}) = 1.55 \times 10^{-8} \Omega \text{m}$

 $RRR = \rho(300K)/\rho(4 \text{ K}) = 300$

 $R_s(4 \text{ K}) \cong 1.3 \text{ m}\Omega$

...in spite of the resistivity decreasing by a factor 300 from 300 K to 4 K, R_s only decreases by a factor of ~8!







Superconductivity

The 3 Hallmarks of Superconductivity

- Zero resistance
- Complete diamagnetism
- Flux quantization





Zero Resistance





Kammerlingh-Onnes, 1911





Complete Diamagnetism







and

Ochsenfeld,

1933



"Meissner effect"





Flux Quantization





and

Deaver

Fairbank,



1961





Critical Temperature

• "Isotope effect" (1950): $T_c \propto 1/\sqrt{M}$, *M*=isotope mass







Two-fluid model

- Gorter and Casimir (1934) two-fluid model: charge carriers are divided in two subsystems, superconducting carriers of density n_s and normal electrons of density n_n.
- The normal current J_n and the supercurrent J_s are assumed to flow in parallel. J_s flows with no resistance.







London equations (I)



F. and H. London, 1935

Superelectrons accelerate steadily in the presence of a constant electric field

 $\lambda_L = 1$

London penetration depth



 $\frac{dJ_s}{dt} = \frac{1}{\mu_0 \lambda_I^2} \vec{E} \qquad \gg \mathbf{E} = 0: \mathbf{J}_s \text{ goes on forever}$ $\Rightarrow \mathbf{E} \text{ is required to maintain an AC current}$





London equations (II)

$$\vec{\nabla} \times \dot{\vec{J}_s} = \frac{1}{\mu_0 \lambda_L^2} \vec{\nabla} \times \vec{E} \qquad \qquad \vec{\nabla} \times \vec{J}_s = -\frac{1}{\mu_0 \lambda_L^2} \dot{\vec{B}} \\ \vec{\nabla} \times \vec{E} = -\dot{\vec{B}} \qquad \qquad \vec{\nabla} \times \vec{E} = -\dot{\vec{B}}$$

$$\vec{\nabla} \times \vec{J}_s = -\frac{1}{\mu_0 \lambda_L^2} \vec{B}$$

B is the source of J_s
 Spontaneus flux exclusion







Coherence length



Local condition between current and field. Valid if $\xi_0 << \lambda_L$ or $l << \lambda_L$

Nonlocal generalization proposed by Pippard in 1953:

$$\vec{J}_{\rm s}(\vec{r}) = -\frac{3}{4\pi\xi_0\lambda_{\rm L}^2} \int_V \frac{\vec{R}\vec{R}\cdot\vec{A}(\vec{r}')e^{-R/\xi}}{R^4} d\vec{r}' \qquad \vec{R} = \vec{r} - \vec{r'}$$

ξ: "**coherence length**", characteristic dimension of the superelectrons wave-function

$$\frac{1}{\xi} = \frac{1}{\xi_0} + \frac{1}{l} \qquad \qquad \xi_0 \propto \frac{\hbar v_F}{kT_c} \qquad \text{for a pure material}$$





The energy gap



Measurements of the electronic specific heat (1954):

- Jump at T_c without any latent heat
- Exponential decrease well below T_c

$$C_{es} \propto e^{-bT/T_c}$$
 b~1.5

Results of measurements of electromagnetic absorption (1956) also consistent with the existence of an **energy gap** Δ , of order kT_c , between the ground state and the excited state of a superconductor





The BCS theory



Bardeen, Cooper and Schrieffer

- In 1958 Bardeen, Cooper and Schrieffer published a theory of superconductivity in which
 - There exists an attractive interaction between electrons, forming "Cooper pairs"
 - This interaction occurs through the exchange of a lattice phonon
 - As a results of this interaction, there exists a bound state with energy lower than $2E_{\rm F}$





Cooper pairs





- Positively charged wake due to moving electron attracting nearby atoms
- This wake can attract another nearby electron
 - a Cooper pair is formed
- Cooper pairs are formed by electrons with opposite momentum and spin
- Cooper pairs belong all to the same quantum state and have the same energy
- When carrying a current, each Cooper pair acquires a momentum which is the same for all pairs
- The **total** momentum of the pair remains constant. It can be changed only if the pair is broken, but this requires a minimum energy 2Δ





Quasi-particles excitations

• The unpaired electrons behave almost like free electrons and are called "quasi-particles"







Energy gap



$$\Delta(T) = \Delta(0) \sqrt{\cos\left(\frac{\pi t^2}{2}\right)}$$

$$t = T/T_{\rm c}$$

 $\Delta(0)/kT_{\rm c} = 1.764$



P. Townsend and J. Sutton, Phys. Rev. 128 (1962) 591.





Characteristic Lengths

• **Coherence length** $\xi_0 \equiv \frac{\hbar v_F}{\pi \Delta(0)}$: interaction distance between electrons forming a Cooper pair $\xi_0 = 39$ nm for Nb

• Penetration depth, $\lambda(T)$: decay length of magnetic field in the superconductor $\lambda(0) = 36$ nm for Nb

$$\lambda(T) = \frac{\lambda_L(0)}{\sqrt{1 - \left(\frac{T}{T_c}\right)^4}}$$





Effect of impurities on ξ and λ

- Adding impurities to a superconductor reduces the normal electrons mean free path, so that the electrodynamic response changes from "clean" (*l* >> ξ) to the "dirty" limit (*l* << ξ).
- Changes in the characteristic lengths of the SC can be approximated as:

$$\frac{1}{\xi} = \frac{1}{\xi_0} + \frac{1}{l}$$
$$\lambda(l, T) = \lambda_L(T) \sqrt{1 + \frac{\xi_0}{l}}$$





Ginzburg-Landau theory



V. Ginzburg



L. Landau

- In 1950 Ginzburg and Landau proposed a theory of SC alternative to the London theory:
 - Near T_c , the difference in the Helmholtz free energy density between SC and NC state can be written as a power series of a complex order parameter, $\psi(\vec{r}) = |\psi(\vec{r})|e^{i\phi(\vec{r})}$



 $n_{\rm p} = |\psi|^2 = n_{\rm s}/2$



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Ginzburg-Landau equations

$$f_{s} = f_{n} + \alpha \left|\psi\right|^{2} + \frac{\beta}{2} \left|\psi\right|^{4} + \frac{1}{2m^{*}} \left|\left(-i\hbar\nabla - e^{*}\mathbf{A}\right)\psi\right|^{2} + \frac{\mu_{0}H^{2}}{2} \qquad \qquad m^{*} = 2m_{e} \\ e^{*} = 2e^{-2}$$

Minimization of f_s with respect to changes in order parameter and magnetic fields results in two equations:

$$\alpha \psi + \beta \left|\psi\right|^2 \psi + \frac{1}{2m^*} \left(-i\hbar \nabla - e^* \mathbf{A}\right)^2 \psi = 0$$

$$\mathbf{J} = \frac{e^*}{m^*} \psi^* \left(-i\hbar \nabla - e^* \mathbf{A} \right) \psi$$

with proper boundary conditions. For example $(-i\hbar\nabla - e^*\mathbf{A})\psi|_n = 0$





Characteristic lengths in GL theory

• GL penetration depth: characteristic length for variation of the magnetic field

$$\lambda_{GL} = \sqrt{\frac{m^*}{\mu_0 \left|\psi\right|^2 e^{*2}}}$$

• GL coherence length: characteristic length for variation of the order parameter

$$\xi_{GL}(T) = \frac{\hbar}{\sqrt{2m^* |\alpha(T)|}} \propto \frac{1}{\sqrt{1-t}}$$

 ξ_{GL} is related to the BCS coherence length (ξ_0):

$$\xi_{GL}(T) \propto \frac{\xi_0}{\sqrt{1-t}}$$
 Clean limit
 $\xi_{GL}(T) \propto \sqrt{\frac{\xi_0 l}{1-t}}$ Dirty limit





Thermodynamic critical field

Superconductivity is lost when a magnetic field applied to a SC increases above a critical value.



Gibbs free energy density in a SC with applied magnetic field H_a :

$$g_s(T,H) = g_s(T,0) + \frac{1}{2}\mu_0 H_a^2$$

at
$$H_a=H_c$$
, $g_s=g_n$

$$H_{c} = \sqrt{\frac{2}{\mu_{0}}} \left[g_{n}(T,0) - g_{s}(T,0) \right]$$

$$H_c(0) = \sqrt{\frac{0.472\gamma}{\mu_0}} T_c \quad \begin{array}{c} \text{from BCS} \\ \text{theory} \end{array}$$

 γ is the Sommerfeld constant



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Critical current

Superconductivity is lost when a current flowing in a SC increases above a critical value.







Phase diagram of SC







The NS boundary energy

Ginzburg-Landau parameter: $\kappa_{GL} = \lambda/\xi_{GL}$



The change in free energy density δf due to the presence of a NS boundary was calculated using GL theory. Qualitatively:

$$\delta f = \frac{\mu_0}{2} (H_0^2 \lambda - H_c^2 \xi)$$

If $\kappa_{GL} > \frac{1}{\sqrt{2}}$, $\delta f < 0$ it is energetically favorable to create NS boundaries within the SC





Type-I and Type-II SC



Abrikosov found solutions $\psi(x, y)$ with periodic zeros = lattice of vortices with **quantized magnetic flux**

 $\Phi_0 = \frac{h}{2e} = 2.07 \times 10^{-15} \, {\rm Wb}$







Flux-line lattice



Triangular flux-line lattice penetrating the top surface of a SC lead-indium sample

The points of exit of the flux lines are decorated by small ferromagnetic particles

H. Träuble and U. Essmann, J. Appl. Phys. 39, 4052 (1968);





Critical fields

$$H_{c} = \frac{\phi_{0}}{2\pi\sqrt{2}\lambda\xi}$$
 Thermodynamic critical field

$$H_{c2} = \sqrt{2}\kappa H_{c} = \frac{\phi_{0}}{2\pi\xi^{2}}$$
 Upper critical field

$$H_{c1} \approx \frac{\phi_{0}}{4\pi\lambda^{2}}\ln(\kappa + \alpha)$$
 Lower critical field

$$\alpha = \frac{1}{2} + \frac{1 + \ln 2}{2\kappa - \sqrt{2} + 2} = \begin{cases} 1.35, \kappa = 0.71\\ 0.5, \kappa \gg 1 \end{cases}$$

For Nb, $\kappa \sim 0.85$, $B_{c1}(0) \sim 180$ mT, $B_{c}(0) \sim 195$ mT, $B_{c2}(0) \sim 400$ mT





Surface barrier

• Condition for entry of the first vortex, parallel to a planar surface (Bean and Livingston, 1964).







Surface critical field

• Saint-James and de Gennes obtained, using the GL theory, that in a magnetic field parallel to the surface, SC will nucleate in a surface layer of thickness $\sim \xi$ at a field $H_{c3} = 1.695H_{c2}$, higher than that at which nucleation occurs in the volume of the material







Type 1.5 Superconductors



- Multi-component SC with $\xi_1 < \lambda < \xi_2$
- Theoretically, vortices can have long-range attractive, short-range repulsive interaction in such material
- "Semi-Meissner state": vortex clusters coexisting with Meissner domains at intermediate fields

Similar phenomenon was observed in low- κ SC (Nb, TaN, PbIn) with the origin of vortex attraction being related to non-local effects (*Type-IIa* or *Type-II/1*)





Surface resistance of SC

• In RF fields, the time-dependent magnetic field in the penetration depth will generate an electric field:

$$\vec{\nabla} \times \vec{E} = -\frac{\partial \vec{B}}{\partial t}$$

• At T > 0 K, there is small fraction of unpaired electrons

 $n_{\rm n}(T) \propto {\rm e}^{-\Delta/{\rm k}_{\rm B}T}$

• Because Cooper pairs have inertia (mass=2m_e) they cannot completely shield nc electrons from this E-field







Surface impedance of superconductors



• Electrodynamics of sc is the same as nc, only that we have to change $\sigma \rightarrow \sigma_1 - i \sigma_2$

• Penetration depth:
$$\delta = \sqrt{\frac{2}{\mu_0 \sigma \omega}} = \frac{1}{\sqrt{\mu_0 \omega \sigma_2}} \sqrt{\frac{2i}{1 - i \sigma_1 / \sigma_2}} \cong (1 + i) \lambda_L \left(1 + i \frac{\sigma_1}{2\sigma_2} \right)$$
$$\sigma_1 << \sigma_2 \text{ for sc at } T << T_c$$
$$H_y = H_0 \exp\left(-\frac{(1 + i)}{\delta} x \right)$$
$$H_y = H_0 e^{-\frac{x}{\lambda_L}} e^{-i \frac{x}{\lambda_L} \frac{\sigma_1}{2\sigma_2}}$$

For Nb, λ_L = 36 nm, compared to δ = 1.7 μ m for Cu at 1.5 GHz

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Surface impedance of superconductors





Surface resistance of superconductor

$$R_s = \frac{1}{2} \mu_0^2 \omega^2 \sigma_1 \lambda_L^3$$

- $R_s \propto \omega^2 \rightarrow$ use low-frequency cavities to reduce power dissipation
- Temperature dependence:



 $n_{s}(T) \propto 1 - (T/T_{c})^{4}$ $\sigma_{1}(T) \propto n_{n}(T) \propto e^{-\Delta/k_{B}T}$

$$R_s \propto \omega^2 \lambda_L^3 l \exp(-\Delta/k_B T)$$
 $T < T_c/2$





Material purity dependence of R_s

• The dependence of the penetration depth on l is approximated as

$$\lambda(l) \approx \lambda_L \sqrt{1 + \frac{\xi_0}{l}}$$

• $\sigma_1 \propto l$

$$\square R_s \propto \left(1 + \frac{\xi_0}{l}\right)^{3/2} l \square R_s \propto l \quad \text{if } l >> \xi_0 \text{ ("clean" limit)} \\ R_s \propto l^{-1/2} \quad \text{if } l << \xi_0 \text{ ("dirty" limit)} \end{aligned}$$

 R_s has a minimum for $l = \xi_0/2$





BCS surface resistance (1)

- Mattis and Bardeen (1958) calculated the perturbed state function using time-dependent perturbation theory.
- Considered only the <u>linear response to weak fields</u> (only terms linear in **A**) so that the perturbation term is:

$$H_1 = \frac{e}{2m} \sum_i \left(\vec{A} \cdot \hat{p}_i + \hat{p}_i \cdot \vec{A} \right)$$





BCS surface resistance (2)

• The following non-local equation between the total current density **J** and the vector potential **A** produced by the

$$\begin{aligned} \operatorname{Re}\{\operatorname{K}(\mathbf{q})\} &= \frac{3}{\hbar v_0 \lambda_{\mathrm{L}0}^2 \mathbf{q}} \times \\ & \left\{ \int_{\max\{\Delta - \hbar \omega, -\Delta\}}^{\Delta} [1 - 2f(E + \hbar \omega)] \{ \frac{E^2 + \Delta^2 + \hbar \omega E}{\sqrt{\Delta^2 - E^2} \sqrt{(E + \hbar \omega)^2 - \Delta^2}} R(a_2, a_1 + b) + S(a_2, a_1 + b) \} dE \\ &+ \frac{1}{2} \int_{\Delta - \hbar \omega}^{-\Delta} [1 - 2f(E + \hbar \omega)] \{ [g(E) + 1] S(a^-, b) - [g(E) - 1] S(a^+, b) \} dE \\ &- \int_{\Delta}^{\infty} [1 - f(E) - f(E + \hbar \omega)] [g(E) - 1] S(a^+, b) dE \\ &+ \int_{\Delta}^{\infty} [f(E) - f(E + \hbar \omega)] [g(E) + 1] S(a^-, b) dE \\ & \left\{ -\frac{1}{2} \int_{\Delta - \hbar \omega}^{-\Delta} [1 - 2f(E + \hbar \omega)] \{ [g(E) + 1] R(a^-, b) + [g(E) - 1] R(a^+, b) \} dE \\ &+ \int_{\Delta}^{\infty} [f(E) - f(E + \hbar \omega)] \{ [g(E) + 1] R(a^-, b) + [g(E) - 1] R(a^+, b) \} dE \\ &+ \int_{\Delta}^{\infty} [f(E) - f(E + \hbar \omega)] \{ [g(E) + 1] R(a^-, b) + [g(E) - 1] R(a^+, b) \} dE \\ \end{array} \end{aligned}$$





BCS surface resistance (2)

- There are numerical codes (Halbritter (1970)) to calculate R_{BCS} as a function of ω , *T* and material parameters (ξ_0 , λ_L , T_c , Δ , *l*)
- For example, check <u>http://www.lepp.cornell.edu/~liepe/webpage/researchsrimp.html</u>
- A good approximation of R_{BCS} for $T < T_c/2$ and $\omega < \Delta/\hbar$ is:

$$R_{\rm BCS} \cong \frac{\mu_0^2 \omega^2 \lambda^3 \sigma_n \Delta}{k_B T} \ln \left[\frac{C_1 k_B T}{\hbar \omega} \right] \exp \left[-\frac{\Delta}{k_B T} \right] \qquad \qquad C_1 = 2.246$$

Let's run some numbers: Nb at 2.0 K, 1.5 GHz $\rightarrow \lambda$ = 36 nm, σ_n = 3.3×10⁸ 1/ Ω m, Δ/k_BT_c = 1.85, T_c = 9.25 K

 $R_{BCS} \cong 20 \text{ n}\Omega \qquad \qquad X_s \cong 0.47 \text{ m}\Omega$

Nb
$$\rightarrow \frac{R_{BCS}(2 \text{ K}, 1.5 \text{ GHz})}{R_s(300 \text{ K}, 1.5 \text{ GHz})} \cong 2 \times 10^{-6}$$





Experimental results



explained by strong coupling effects, anisotropic energy gap in the presence of impurity scattering or by inhomogeneities

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density of impurities at the cavity surface.



Residual resistance



For Nb, R_{res} (~1-10 n Ω) dominates R_s at low frequency (f < ~750 MHz) and low temperature (T < ~2.1 K)





BCS surface reactance

$$X_{s} = \omega \mu_{0} \lambda \qquad \qquad \frac{\sigma_{2}}{\sigma_{n}} = \frac{1}{\omega \mu_{0} \sigma_{n} \lambda^{2}} = \frac{\delta^{2}}{2\lambda^{2}}$$

• A good approximation of σ_2 for $T < T_c/2$ and $\omega < \Delta/\hbar$ is:







RF critical field: superheating field



- Penetration and oscillation of vortices under the RF field gives rise to strong dissipation and the surface resistance of the order of R_s in the normal state
- the Meissner state can remain metastable at higher fields, $H > H_{c1}$ up to the <u>superheating field</u> H_{sh} at which the Bean-Livingston surface barrier for penetration of vortices disappears and the Meissner state becomes unstable

 $H_{\rm sh}$ is the maximum magnetic field at which a type-II superconductor can remain in a true non-dissipative state not altered by dissipative motion of vortices.

At $H = H_{\rm sh}$ the screening surface current reaches the depairing value $J_{\rm d} = n_{\rm s} e \Delta / p_{\rm F}$





Superheating field: theory

• Calculation of $H_{\rm sh}(\kappa)$ from Ginzburg-Landau theory $(T \approx T_{\rm c})$

[Matricon and Saint-James (1967)]:



Time evolution of the spatial pattern of the order parameter in a small region around the boundary where a vortex entrance is taking place, calculated from time-dependent GL-equations.

 $H_{sh} \approx 1.2 H_c, \quad \kappa \cong 1$

 $H_{sh} \approx 0.745 H_c, \quad \kappa >> 1$









A. D. Hernandez and D. Dominguez, Phys. Rev. B **65**, 144529 (2002)





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Superheating field: theory

• Calculation of $H_{sh}(T, l)$ for $\kappa \gg 1$ from Eilenberger equations $(0 < T < T_c)$ [Pei-Jen Lin and Gurevich (2012)]:



 $\alpha = \pi \xi_0 / l$ Impurity scattering parameter

$$H_{sh} \approx 0.845 H_c$$

$$H_{sh}(T) \cong H_{sh}(0) \left[1 - \left(\frac{T}{T_c} \right)^2 \right]$$

F. Pei-Jen Lin and A. Gurevich, Phys. Rev. B 85, 054513 (2012)

• Weak dependence of $H_{\rm sh}$ on non-magnetic impurities





Superheating field: experimental results

 Use high-power (~1 MW) and short (~100 μs) RF pulses to achieve the metastable state before other loss mechanisms kick-in



• RF magnetic fields higher than H_{c1} have been measured in both Nb and Nb₃Sn cavities. However max H_{RF} in Nb₃Sn is << predicted H_{sh} ...





Field dependence of R_s: Experimental results





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R_s at High Field



• Unlike in the moderately dirty limit, in a clean SC the quasiparticle density of states become that of a normal-conductor (gapless) at $H < H_{sh}$





Effect of Impurities on R_s at High Field



 $R_s(H) \propto \exp(-\varepsilon_g(H)/kT)$

Impurities in the top ~40nm layer of Nb can decrease the non-linearity of $R_{\rm s}$ at high fields





Recent breakthroughs...





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Nonlinear R_s at high-field

- A. Gurevich published last year a theory of non-linear Rs at high field [A. Gurevich, *Phys. Rev. Lett.* **113**, 087001 (2014)]
- $R_{\rm s}(H)$ was re-derived from first principles (BCS) taking into account oscillations of $N(\varepsilon, t)$ due to RF current pairbreaking and non-equilibrium distribution function of quasiparticles in the dirty limit

See talk by A. Gurevich on Wednesday, 8:00 am





Performance limitations







References

- Recommended references:
 - M. Tinkham, *Introduction to Superconductivity*, McGraw-Hill, New York, 2nd edition, 1996
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 - A. Gurevich, "Superconducting Radio-Frequency Fundamentals for Particle Accelerators", *Rev. Accel. Sci. Tech.* 5, 119 (2012)

Thank you for your attention!



